

General Description

The WSD30L40DN is the highest performance trench P-ch MOSFETs with extreme high cell density, which provide excellent RDSON and gate charge for most of the synchronous buck converter applications.

The WSD30L40DN meet the RoHS and Green Product requirement 100% EAS guaranteed with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

Absolute Maximum Ratings

| Symbol | Parameter | Rating | | Units |
|-----------------------|---|------------|--------------|------------|
| | | 10s | Steady State | |
| V_{DS} | Drain-Source Voltage | -30 | | V |
| V_{GS} | Gate-Source Voltage | ± 20 | | V |
| $I_D@T_C=25^\circ C$ | Continuous Drain Current, $V_{GS} @ -10V^1$ | -40 | | A |
| $I_D@T_C=100^\circ C$ | Continuous Drain Current, $V_{GS} @ -10V^1$ | -25 | | A |
| $I_D@T_A=25^\circ C$ | Continuous Drain Current, $V_{GS} @ -10V^1$ | -14.5 | -12 | A |
| $I_D@T_A=70^\circ C$ | Continuous Drain Current, $V_{GS} @ -10V^1$ | -10.5 | -9.8 | A |
| I_{DM} | Pulsed Drain Current ² | -70 | | A |
| EAS | Single Pulse Avalanche Energy ³ | 81 | | mJ |
| I_{AS} | Avalanche Current | -18 | | A |
| $P_D@T_C=25^\circ C$ | Total Power Dissipation ⁴ | 32.9 | | W |
| $P_D@T_A=25^\circ C$ | Total Power Dissipation ⁴ | 3.6 | 3.1 | W |
| T_{STG} | Storage Temperature Range | -55 to 150 | | $^\circ C$ |
| T_J | Operating Junction Temperature Range | -55 to 150 | | $^\circ C$ |

Thermal Data

| Symbol | Parameter | Typ. | Max. | Unit |
|-----------------|--|------|------|--------------|
| $R_{\theta JA}$ | Thermal Resistance Junction-Ambient ¹ | --- | 75 | $^\circ C/W$ |
| $R_{\theta JA}$ | Thermal Resistance Junction-Ambient ¹ (t ≤ 10s) | --- | 40 | $^\circ C/W$ |
| $R_{\theta JC}$ | Thermal Resistance Junction-Case ¹ | --- | 3.8 | $^\circ C/W$ |

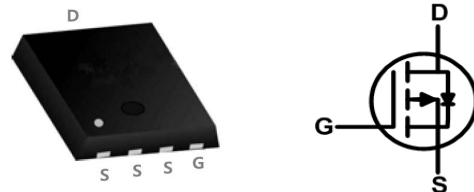
Product Summary

| BVDSS | RDSON | ID |
|-------|-------|------|
| -30V | 11mΩ | -40A |

Applications

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

DFN3X3-8 Pin Configuration



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|-------------------------------------|--|--|------|---------|------|-------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, I _D =-250uA | -30 | --- | --- | V |
| ΔBV _{DSS} /ΔT _J | BVDSS Temperature Coefficient | Reference to 25°C, I _D =-1mA | --- | -0.0232 | --- | V/°C |
| R _{DS(ON)} | Static Drain-Source On-Resistance ² | V _{GS} =-10V, I _D =-20A | --- | 11 | 14 | mΩ |
| | | V _{GS} =-4.5V, I _D =-10A | --- | 18 | 24 | |
| V _{GS(th)} | Gate Threshold Voltage | V _{GS} =V _{DS} , I _D =-250uA | -1.3 | -1.8 | -2.3 | V |
| ΔV _{GS(th)} | V _{GS(th)} Temperature Coefficient | | --- | 4.6 | --- | mV/°C |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =-24V, V _{GS} =0V, T _J =25°C | --- | --- | -1 | uA |
| | | V _{DS} =-24V, V _{GS} =0V, T _J =55°C | --- | --- | -5 | |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} =±20V, V _{DS} =0V | --- | --- | ±100 | nA |
| g _{fs} | Forward Transconductance | V _{DS} =-5V, I _D =-30A | --- | 15 | --- | S |
| R _g | Gate Resistance | V _{DS} =0V, V _{GS} =0V, f=1MHz | --- | 9 | --- | Ω |
| Q _g | Total Gate Charge (-4.5V) | V _{DS} =-15V, V _{GS} =-4.5V, I _D =-20A | --- | 30 | --- | nC |
| Q _{gs} | Gate-Source Charge | | --- | 1.2 | --- | |
| Q _{gd} | Gate-Drain Charge | | --- | 11 | --- | |
| T _{d(on)} | Turn-On Delay Time | V _{DD} =-15V, V _{GS} =-10V, R _G =6Ω I _D =-1A, R _L =15Ω | --- | 11 | --- | ns |
| T _r | Rise Time | | --- | 11 | --- | |
| T _{d(off)} | Turn-Off Delay Time | | --- | 101 | --- | |
| T _f | Fall Time | | --- | 60 | --- | |
| C _{iss} | Input Capacitance | V _{DS} =-15V, V _{GS} =0V, f=1MHz | --- | 1380 | --- | pF |
| C _{oss} | Output Capacitance | | --- | 280 | --- | |
| C _{rss} | Reverse Transfer Capacitance | | --- | 217 | --- | |

Guaranteed Avalanche Characteristics

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|--------|--|---|------|------|------|------|
| EAS | Single Pulse Avalanche Energy ⁵ | V _{DD} =-25V, L=0.5mH, I _{AS} =-18A | 78 | --- | --- | mJ |

Diode Characteristics

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|-----------------|--|--|------|------|------|------|
| I _S | Continuous Source Current ^{1,6} | V _G =V _D =0V, Force Current | --- | --- | -20 | A |
| I _{SM} | Pulsed Source Current ^{2,6} | | --- | --- | -70 | A |
| V _{SD} | Diode Forward Voltage ² | V _{GS} =0V, I _S =-1A, T _J =25°C | --- | --- | -1 | V |
| t _{rr} | Reverse Recovery Time | I _F =-20A, dI/dt=100A/μs, T _J =25°C | --- | 20 | --- | nS |
| Q _{rr} | Reverse Recovery Charge | | --- | 8 | --- | nC |

Note :

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper, t_≤10sec.
- 2.The data tested by pulsed, pulse width ≤ 300us, duty cycle ≤ 2%
- 3.The EAS data shows Max. rating. The test condition is V_{DD}=-25V, V_{GS}=-10V, L=0.5mH, I_{AS}=-18A
- 4.The power dissipation is limited by 150°C junction temperature
- 5.The Min. value is 100% EAS tested guarantee.
- 6.The data is theoretically the same as I_D and I_{DM}, in real applications, should be limited by total power dissipation.

Typical Characteristics

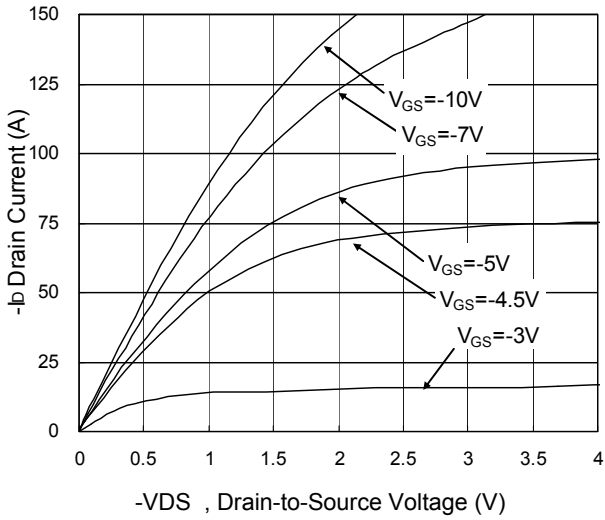


Fig.1 Typical Output Characteristics

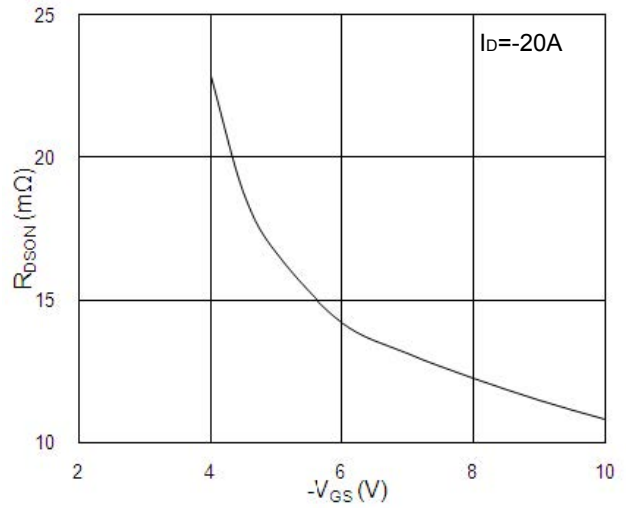


Fig.2 On-Resistance vs. G-S Voltage

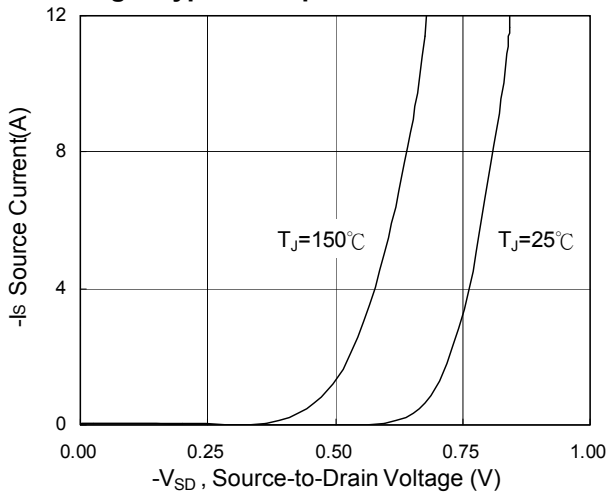


Fig.3 Forward Characteristics of Reverse

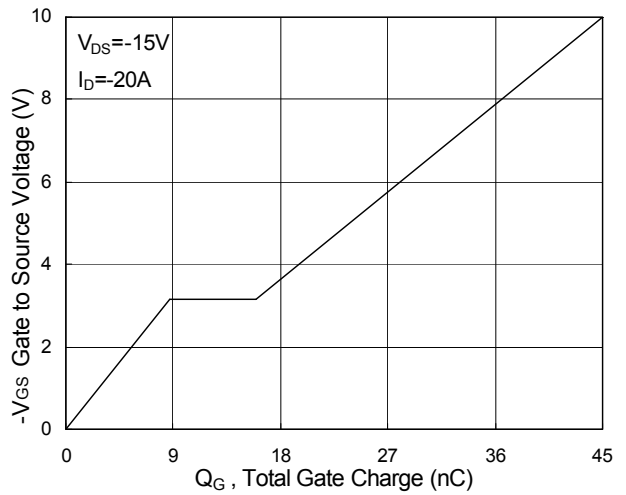


Fig.4 Gate-Charge Characteristics

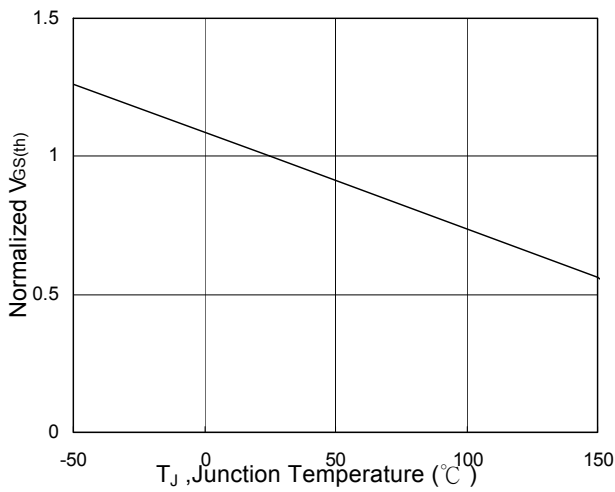


Fig.5 Normalized $V_{GS(th)}$ vs. T_J

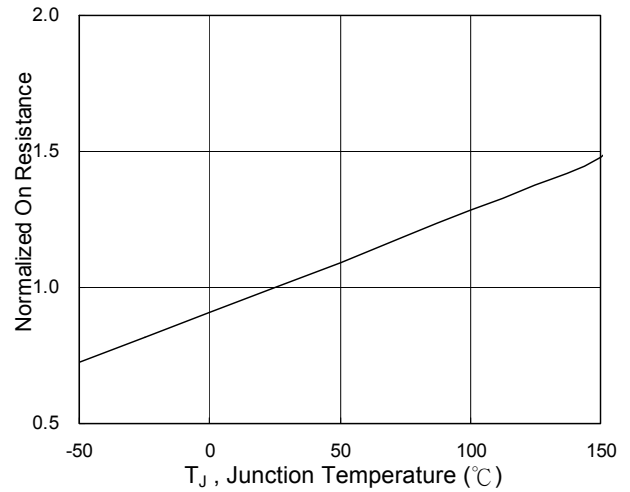


Fig.6 Normalized $R_{DS(on)}$ vs. T_J

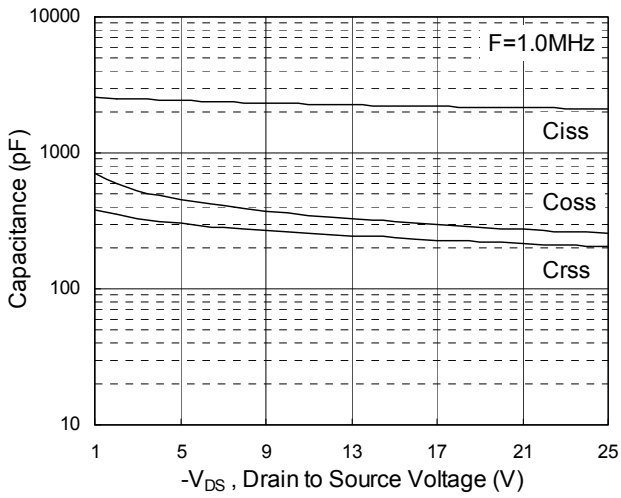


Fig.7 Capacitance

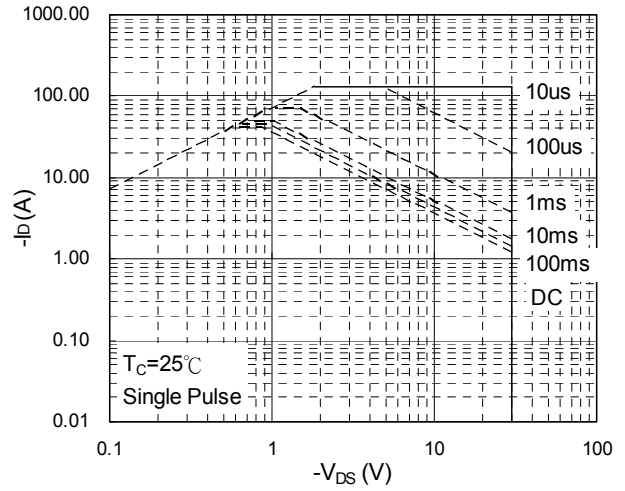


Fig.8 Safe Operating Area

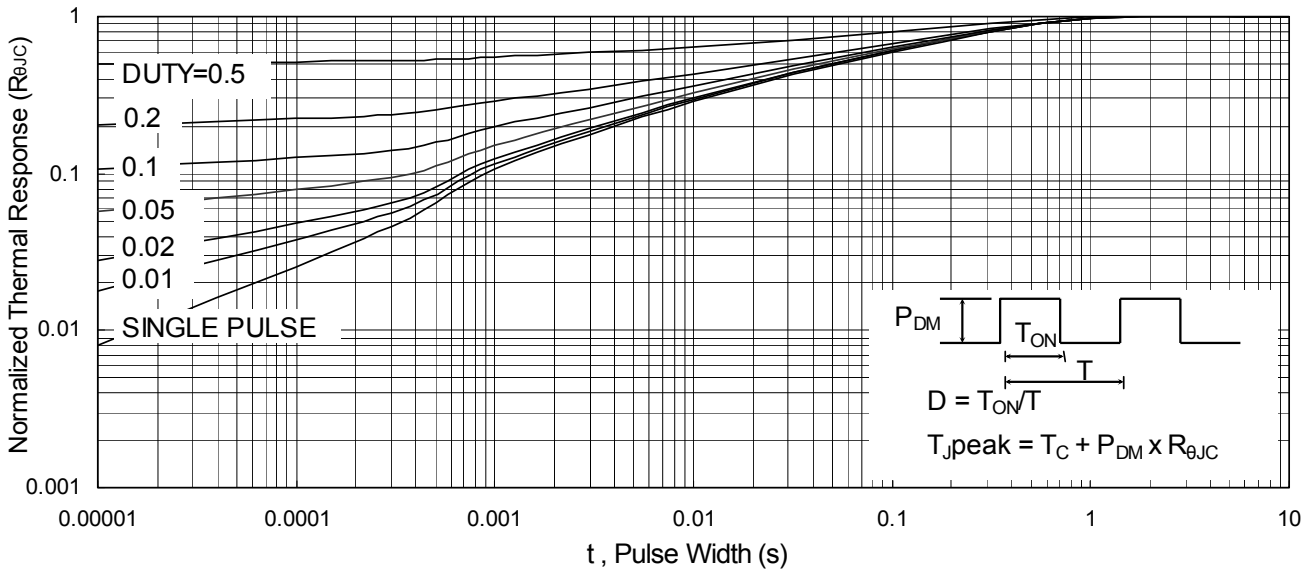


Fig.9 Normalized Maximum Transient Thermal Impedance

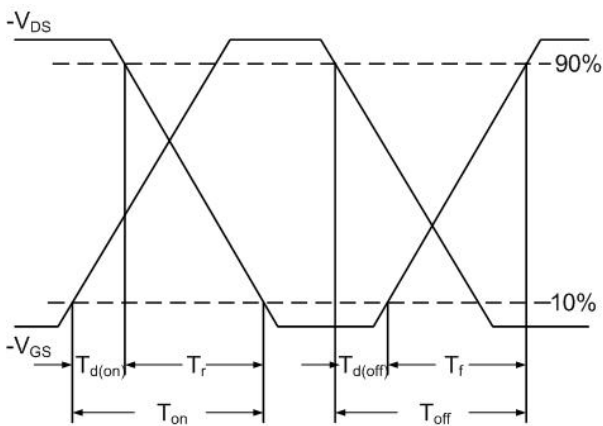


Fig.10 Switching Time Waveform

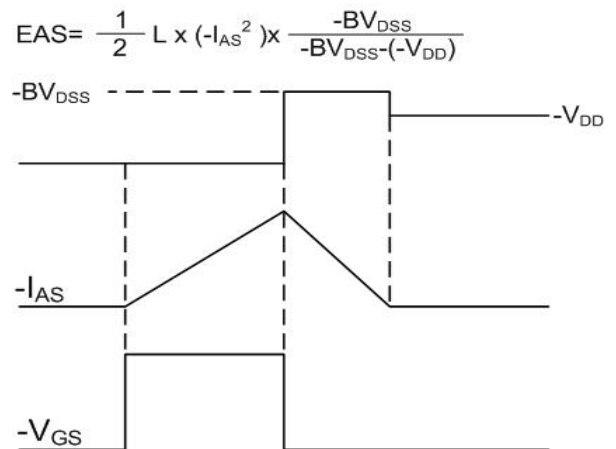


Fig.11 Unclamped Inductive Switching Waveform



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